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NEC **NPN SILICON POWER TRANSISTOR**
2SD882

DESCRIPTION The 2SD882 is NPN silicon transistor suited for its listed range of 3 volt audio amplifier, output impedance: 500 Ω, low noise and high gain.

FEATURES

- Low saturation voltage
 $V_{CE(sat)}$ @ $I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$
- High frequency characteristics and high gain
 f_T @ $I_C = 10\text{ mA}$, $V_{CE} = 5\text{ V}$, $I_B = 1\text{ mA}$
- Low operating noise, excellent linearity and low distortion and excellent frequency characteristics for a silicon transistor.

ABSOLUTE MAXIMUM RATINGS

Maximum Temperature	150 °C
Storage Temperature	-55 to 150 °C
Operating Temperature	-55 to 100 °C
Maximum Power Dissipation	1.0 W
Case Temperature (T _C) = 25 °C	
Single Pulse Dissipation (T _C = 25 °C)	10 W
Maximum Storage and Handling (T _C = 25 °C)	10 W
V _{CE} Collector to Base Voltage	30 V
V _{CE} Collector to Emitter Voltage	30 V
V _{BE} Base to Emitter Voltage	5 V
V _{BE} Collector to Base Voltage	5 V
V _{BE} Collector to Emitter Voltage	5 V
V _{BE} Base to Collector Voltage	5 V

ELECTRICAL CHARACTERISTICS (T_C = 25 °C)

Symbol	Parameter	Min.	Typ.	Max.	Test Conditions
I_C	Collector Current	100	100	100	$V_{CE} = 5\text{ V}$, $I_B = 10\text{ mA}$
I_B	Base Current	10	10	10	$V_{CE} = 5\text{ V}$, $I_C = 100\text{ mA}$
f_T	Transition Frequency	100	100	100	$V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	0.2	0.2	0.2	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$
V_{BE}	Base to Emitter Saturation Voltage	0.6	0.6	0.6	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$
V_{BE}	Collector to Base Saturation Voltage	0.6	0.6	0.6	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$
V_{BE}	Collector to Emitter Saturation Voltage	0.6	0.6	0.6	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$
V_{BE}	Base to Collector Saturation Voltage	0.6	0.6	0.6	$I_C = 100\text{ mA}$, $I_B = 10\text{ mA}$

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